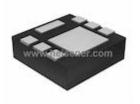




RF4E080BNTR Information



For Reference Only

Part Number RF4E080BNTR

Manufacturer Rohm Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 8A 8-HUML

Package 8-PowerUDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









RF4E080BNTR Specifications

Manufacturer Part Number	RF4E080BNTR
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerUDFN
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	8A (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	14.5nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	660pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2W (Ta)
Rds On (Max) @ Id, Vgs	17.6 mOhm @ 8A, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	6-HUML2020L8 (2x2)
Package / Case	8-PowerUDFN
	Report errors?

RF4E080BNTR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

RF4E080BNTR Payment Methods





















RF4E080BNTR Shipping Methods













If you have any question about RF4E080BNTR, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com